



#### **465V NPN HIGH VOLTAGE POWER TRANSISTOR**

#### **Features**

- BV<sub>CEO</sub> > 465V
- BV<sub>CES</sub> > 700V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 1.5A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <a href="https://www.diodes.com/quality/product-definitions/">https://www.diodes.com/quality/product-definitions/</a>

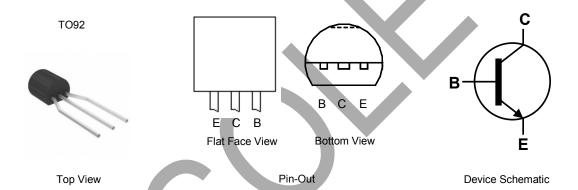
#### **Mechanical Data**

- Case: TO92 (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 ©3
- Weight: 200mg (Approximate)

#### **Applications**

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting



## Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13003EZTR-G1	TO92 (Joggled Legs)	13003EZ-G1	2,000 Taped, per Ammo Box

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

13003E
Z-G1
YWW8XX

Flat Face View

TO92

= Manufacturers' code marking
 13003EZ-G1 = Product Type Marking ID
 YWW = Date Code Marking
 e.g. 312 = Year 2013, Week 12.
 8 = Assembly site code
 XX = Batch Number

APT13003E
Datasheet Number: DS36304 Rev. 4 - 4



#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0V)	$V_{CES}$	700	V
Collector-Emitter Voltage	$V_{\sf CEO}$	465	V
Emitter-Base Voltage	$V_{EBO}$	9	V
Continuous Collector Current	Ic	1.5	Α
Peak Pulse Collector Current (Note 5)	Ісм	3	Α
Continuous Base Current	l <sub>Β</sub>	0.75	Α
Peak Pulse Base Current (Note 5)	I <sub>BM</sub>	1.5	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

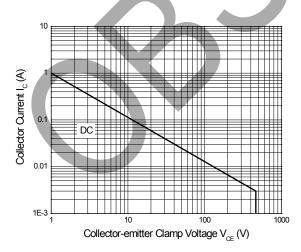
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	1.1	W
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	113.6	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 5. Pulse test for pulse width < 5ms, duty cycle ≤ 10%. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Safe Operating Area (@TA = +25°C, unless otherwise specified.)



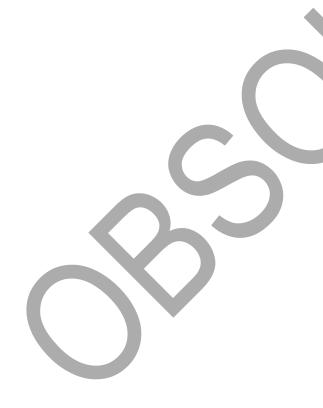
Safe Operating Areas (TO92 Package)



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

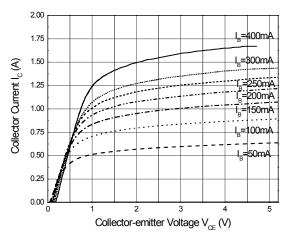
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	_	_	V	I <sub>C</sub> = 100μA, V <sub>BE</sub> = 0V
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	465	_	_	V	I <sub>C</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	_	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CEV</sub>	_	_	10	μΑ	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
		15	_	_	_	$I_C = 0.3A$ , $V_{CE} = 2V$
DC Current Transfer Static Ratio (Note 7)	h <sub>FE</sub>	13	17	30	_	$I_C = 0.5A, V_{CE} = 2V$
		5	_	25		$I_C = 1.0A, V_{CE} = 2V$
Callegator Fraitter Cataration Valtage (Nata 7)	.,	_	0.17	0.3	V	$I_C = 0.5A$ , $I_B = 0.1A$
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	_	0.29	0.4	V	$I_C = 1A$ , $I_B = 0.25A$
Dago Emitter Seturation Voltage (Note 7)	W	_	_	1.0	V	I <sub>C</sub> = 0.5A, I <sub>B</sub> = 0.1A
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	_	_	1.2	V	$I_C = 1A$ , $I_B = 0.25A$
Output Capacitance	C <sub>obo</sub>	_	16	-	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	_		MHz	I <sub>C</sub> = 0.1A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	t <sub>on</sub>	_	0.3	1		
Storage Time with Resistive Load	t <sub>s</sub>	_	1.8	3	μs	$I_C$ = 1A, $V_{CC}$ = 125V, $I_{B1}$ = 0.2A, $I_{B2}$ = -0.2A, $I_p$ = 25 $\mu$ s
Fall Time with Resistive Load	t <sub>f</sub>	_	0.28	0.4		1820.2Λ, ιρ - 20μ5

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

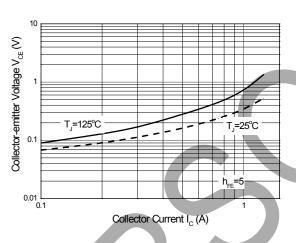




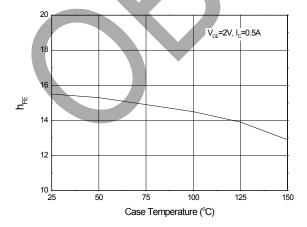
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



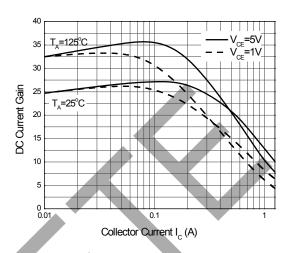
Static Characteristics



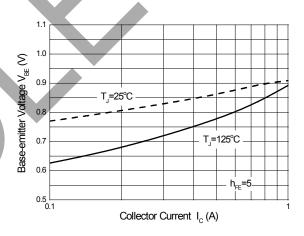
Collector-emitter Saturation Voltage



hFE vs. Case Temperature



DC Current Gain vs. Collector Current



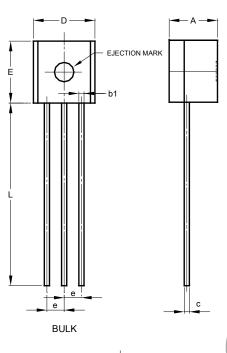
Base-emitter Saturation Voltage

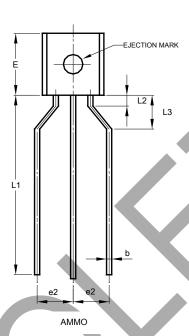


### **Package Outline Dimensions**

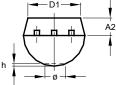
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO92 (Type C)





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TO92 (Type C)						
Dim	Min	Max	Тур			
Α	3.30	3.70	-			
A2	1.10	1.40	-			
b	0.38	0.55	-			
С	0.36	0.51	-			
ם	4.40	4.70	1			
D1	3.430	ı	-			
Е	4.30	4.70	-			
е	-	-	1.27			
e2	2.440	2.640	-			
h	0.00	0.38	-			
L	14.10	14.50	-			
L1	12.50	14.50	-			
L3	2.50	3.50	-			
Ø	-	1.60	-			
All Dimensions in mm						



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



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